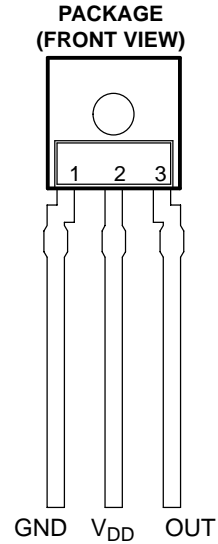


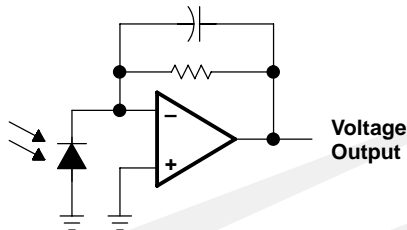
- Integral Visible Light Cutoff Filter
- Monolithic Silicon IC Containing Photodiode, Operational Amplifier, and Feedback Components
- Converts Light Intensity to a Voltage
- High Irradiance Responsivity, Typically $111 \text{ mV}/(\mu\text{W}/\text{cm}^2)$ at $\lambda_p = 940 \text{ nm}$ (TSL260R)
- Compact 3-Lead Plastic Package
- Single Voltage Supply Operation
- Low Dark (Offset) Voltage....10mV Max
- Low Supply Current.....1.1 mA Typical
- Wide Supply-Voltage Range.... 2.7 V to 5.5 V
- Replacements for TSL260, TSL261, and TSL262



Description

The TSL260R, TSL261R, and TSL262R are infrared light-to-voltage optical sensors, each combining a photodiode and a transimpedance amplifier (feedback resistor = 16 MΩ, 8 MΩ, and 2.8 MΩ respectively) on a single monolithic IC. Output voltage is directly proportional to the light intensity (irradiance) on the photodiode. These devices have improved amplifier offset-voltage stability and low power consumption and are supplied in a 3-lead plastic sidelooker package with an integral visible light cutoff filter and lens.

Functional Block Diagram



Terminal Functions

TERMINAL NAME	NO.	DESCRIPTION
GND	1	Ground (substrate). All voltages are referenced to GND.
OUT	3	Output voltage
V _{DD}	2	Supply voltage

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Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD} (see Note 1)	6 V
Output current, I_O	± 10 mA
Duration of short-circuit current at (or below) 25°C (see Note 2)	5 s
Operating free-air temperature range, T_A	-25°C to 85°C
Storage temperature range, T_{stg}	-25°C to 85°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	240°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to GND.
2. Output may be shorted to supply.

Recommended Operating Conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{DD}	2.7		5.5	V
Operating free-air temperature, T_A	0		70	°C

Electrical Characteristics at $V_{DD} = 5$ V, $T_A = 25^\circ\text{C}$, $\lambda_p = 940$ nm, $R_L = 10$ k Ω (unless otherwise noted) (see Notes 3, 4, and 5)

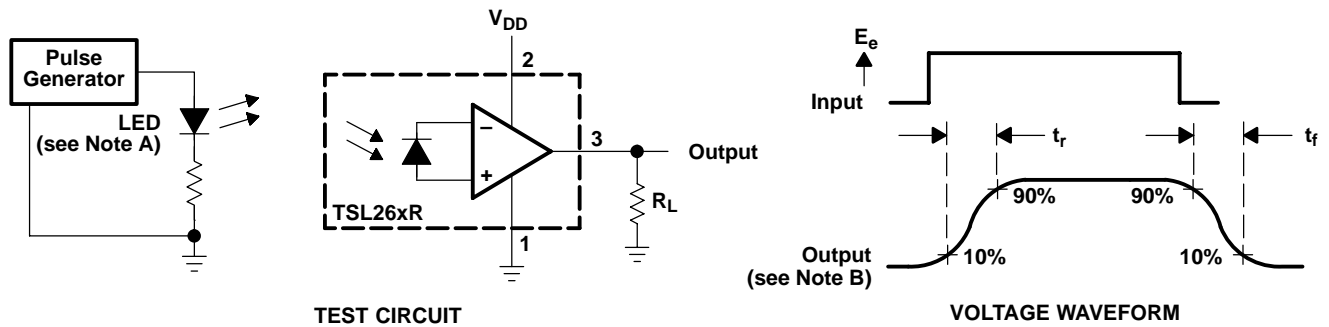
PARAMETER	TEST CONDITIONS	TSL260R			TSL261R			TSL262R			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_D Dark voltage	$E_e = 0$	0	4	10	0	4	10	0	4	10	mV
V_{OM} Maximum output voltage	$V_{DD} = 4.5$ V	3	3.3		3	3.3		3	3.3		V
V_O Output voltage	$E_e = 18 \mu\text{W}/\text{cm}^2$	1	2	3							V
	$E_e = 46 \mu\text{W}/\text{cm}^2$				1	2	3				
	$E_e = 220 \mu\text{W}/\text{cm}^2$							1	2	3	
α_{vo} Temperature coefficient of output voltage (V_O)	$E_e = 18 \mu\text{W}/\text{cm}^2$, $T_A = 0^\circ\text{C}$ to 70°C	8									mV/°C
		0.4									%/°C
	$E_e = 46 \mu\text{W}/\text{cm}^2$, $T_A = 0^\circ\text{C}$ to 70°C				8						mV/°C
					0.4						%/°C
$E_e = 220 \mu\text{W}/\text{cm}^2$, $T_A = 0^\circ\text{C}$ to 70°C							8			mV/°C	
							0.4			%/°C	
N_e Irradiance responsivity	See Note 6	111			43.5			9.1			mV/($\mu\text{W}/\text{cm}^2$)
I_{DD} Supply current	$E_e = 18 \mu\text{W}/\text{cm}^2$	1.1			1.7						mA
	$E_e = 46 \mu\text{W}/\text{cm}^2$				1.1			1.7			
	$E_e = 220 \mu\text{W}/\text{cm}^2$							1.1			

- NOTES: 3. Measurements are made with $R_L = 10$ k Ω between output and ground.
4. Optical measurements are made using small-angle incident radiation from an LED optical source.
5. The input irradiance E_e is supplied by a GaAs LED with peak wavelength $\lambda_p = 940$ nm
6. Irradiance responsivity is characterized over the range $V_O = 0.05$ to 2.9 V. The best-fit straight line of Output Voltage V_O versus irradiance E_e over this range will typically have a positive extrapolated V_O value for $E_e = 0$.

Dynamic Characteristics at $T_A = 25^\circ\text{C}$ (see Figure 1)

PARAMETER	TEST CONDITIONS	TSL260R			TSL261R			TSL262R			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_r Output pulse rise time	$V_{DD} = 5\text{ V}$, $\lambda_p = 940\text{ nm}$		260		70		7				μs
t_f Output pulse fall time	$V_{DD} = 5\text{ V}$, $\lambda_p = 940\text{ nm}$		260		70		7				μs
V_n Output noise voltage	$V_{DD} = 5\text{ V}$, $E_e = 0$, $f = 1000\text{ Hz}$		0.8		0.7		0.6				$\mu\text{V}/\sqrt{\text{Hz}}$

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input irradiance is supplied by a pulsed GaAs light-emitting diode with the following characteristics: $\lambda_p = 940\text{ nm}$, $t_r < 1\ \mu\text{s}$, $t_f < 1\ \mu\text{s}$.

B. The output waveform is monitored on an oscilloscope with the following characteristics: $t_r < 100\text{ ns}$, $Z_i \geq 1\ \text{M}\Omega$, $C_i \leq 20\ \text{pF}$.

Figure 1. Switching Times

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TYPICAL CHARACTERISTICS

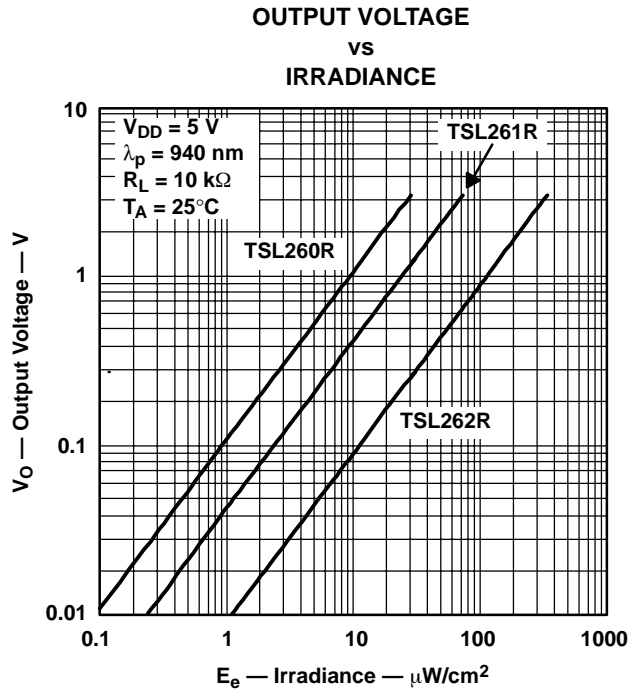


Figure 2

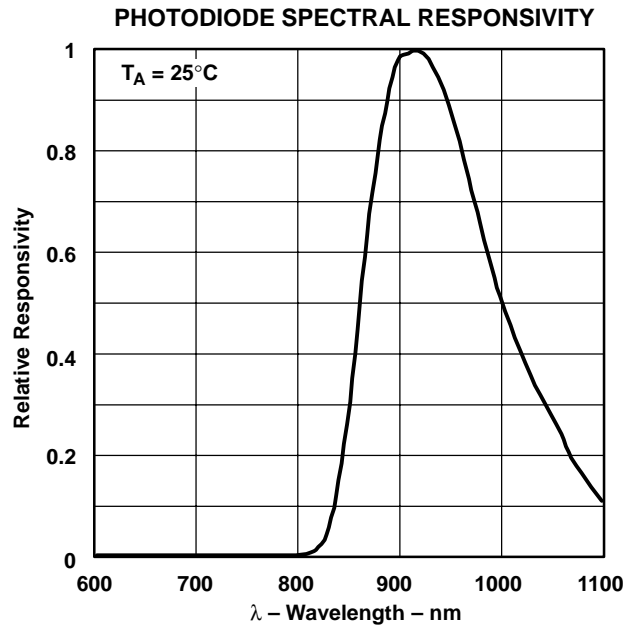


Figure 3

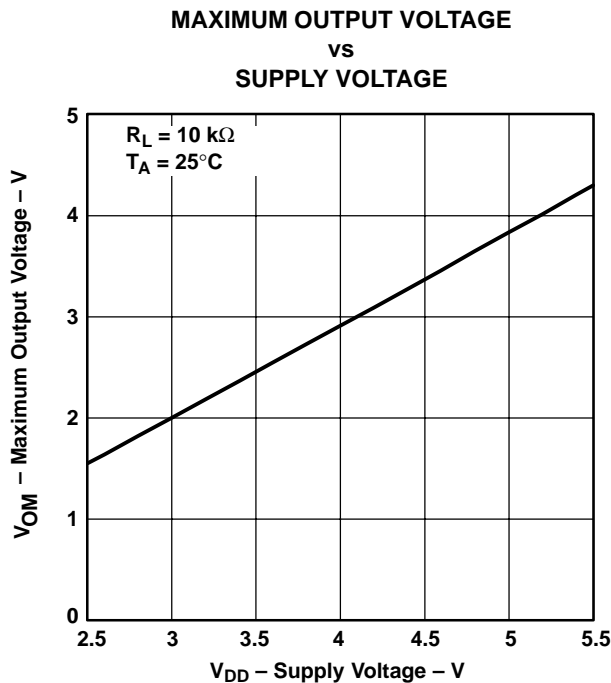


Figure 4

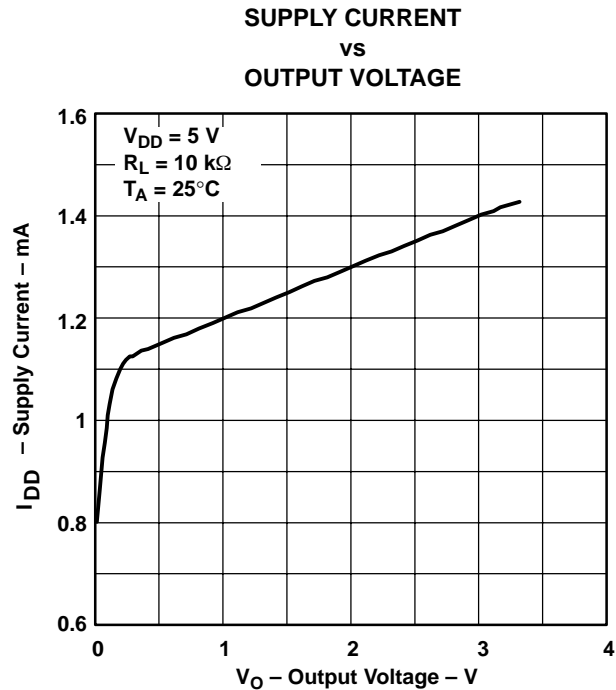


Figure 5

TYPICAL CHARACTERISTICS

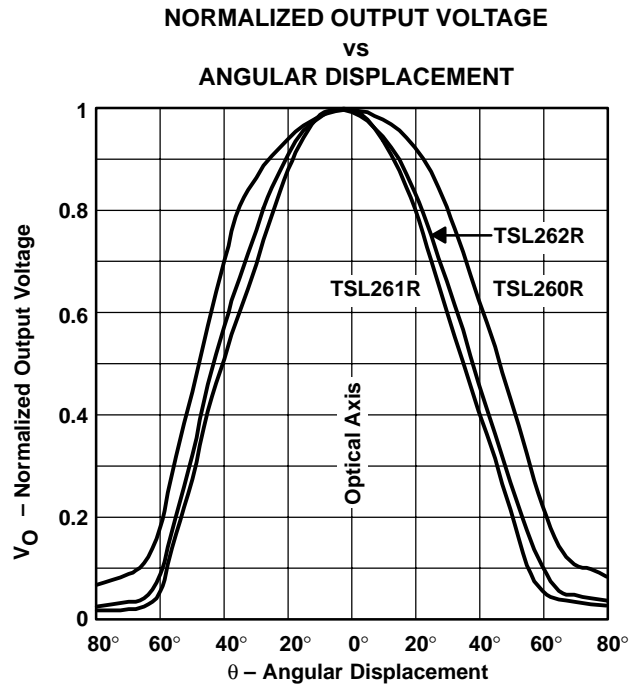


Figure 6

TSL260R, TSL261R, TSL262R INFRARED LIGHT-TO-VOLTAGE OPTICAL SENSORS

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MECHANICAL INFORMATION

The device is supplied in a plastic three-lead package. The integrated photodiode active area is typically 1,0 mm² (0.0016 in²) for TSL260R, 0,5 mm² (0.00078 in²) for the TSL261R, and 0,26 mm² (0.0004 in²) for the TSL262R.

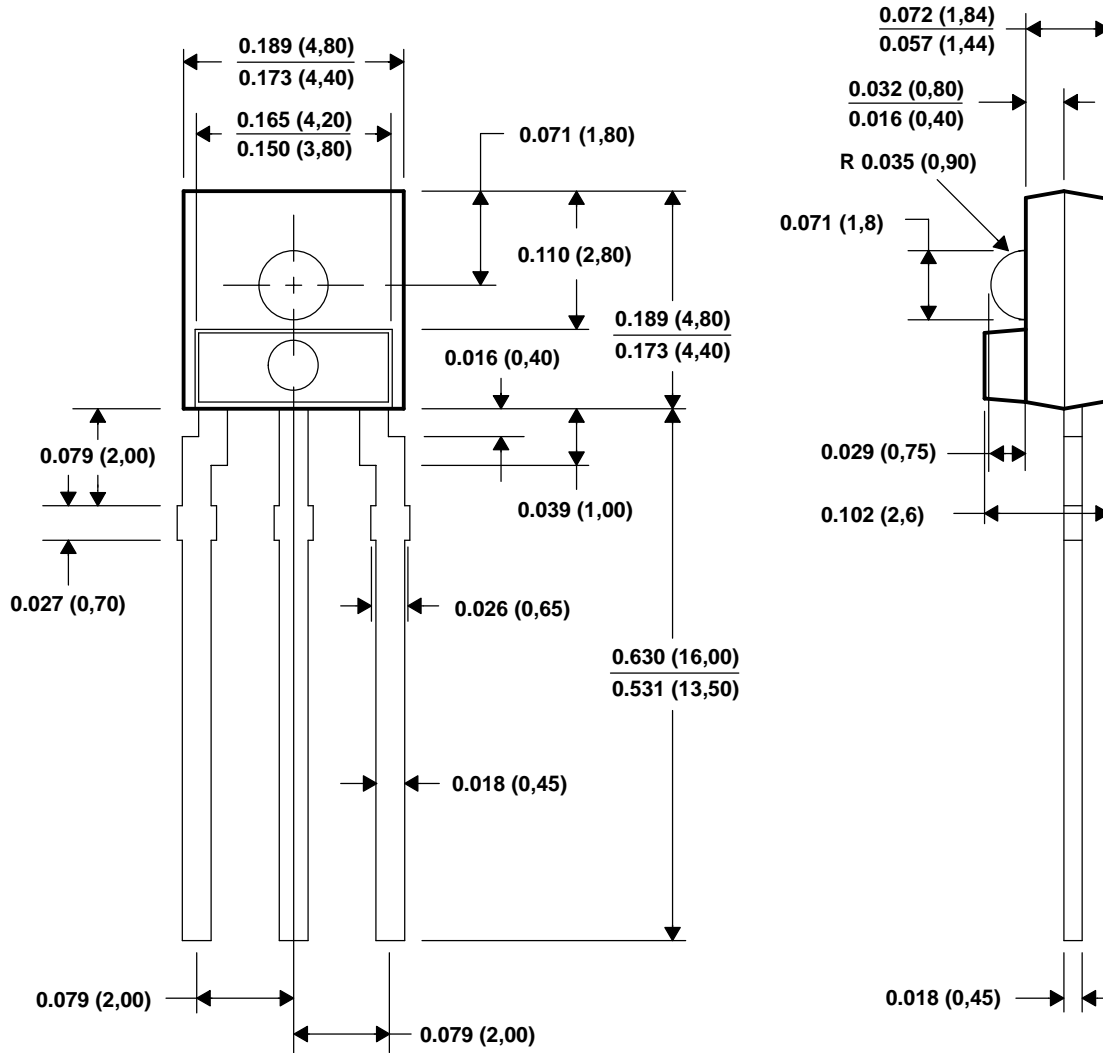


Figure 7. Package Configuration

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. All dimensions apply before solder dip.
 - C. Package body is a nonfilled optically transparent material
 - D. Index of refraction of clear plastic is 1.55.
 - E. This drawing is subject to change without notice.

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TSL260R, TSL261R, TSL262R INFRARED LIGHT-TO-VOLTAGE OPTICAL SENSORS

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